

Comment on “Dielectric tunability of (110) oriented barium strontium titanate epitaxial films on (100) orthorhombic substrates” [Appl. Phys. Lett. 89, 042903 (2006)]

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Comment on “Dielectric tunability of (110) oriented barium strontium titanate epitaxial films on (100) orthorhombic substrates” [Appl. Phys. Lett. 89, 042903 (2006)]

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A modified thermodynamic potential was derived to describe the phase states and dielectric properties of (110) oriented epitaxial films grown on orthorhombic substrates.
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In a recent letter Akcay *et al.*¹ applied a nonlinear thermodynamic theory to calculate the dielectric properties of (110) oriented ferroelectric films grown on (100) orthorhombic substrates. But there are doubts about the correctness of the thermodynamic potential derived in Ref. 1 for such epitaxial films.

Firstly, the sixth-order terms in this potential [Eq. (4) in Ref. 1] conform to the symmetry of the cubic paraelectric phase. But in the reference frame used by the authors the symmetry of (110) freestanding film differs from the cubic one (Evidently, in this reference frame the symmetry of unconstrained ferroelectric layer is tetragonal). For the discussed case the use of the elastic Gibbs function G in its standard form² is incorrect since this form is not invariant with respect to rotation introduced by the transformation matrix (10) in Ref. 1.

Secondly, the limit of the expressions for renormalized coefficients $\tilde{\alpha}_i$ for a cubic film with principal axes parallel to the ones of the substrate must coincide with the formulas obtained earlier for (001) oriented film.³ [This limit can be easily obtained by settings $C_{11}=C_{22}=C_{33}$, $C_{12}=C_{13}=C_{23}$, $Q_{11}=Q_{22}$, $Q_{12}=Q_{13}=Q_{23}$ at the expressions (5) in Ref. 1]. However, the coincidence was not found.

The expression for modified thermodynamic potential \tilde{G} which correctly takes into account the boundary conditions and the orientation of the film can be obtained by the Legendre transformation⁴ of the Gibbs free energy function rewritten in the film reference frame (x_1, x_2, x_3). Applying this procedure we obtain the following expression for effective thermodynamic potential of (110) oriented films (the contributions independent of the polarization are omitted):

$$\begin{aligned}\tilde{G} = & \alpha_1^* P_1^2 + \alpha_2^* P_2^2 + \alpha_3^* P_3^2 + \Delta\alpha_{11}^* P_1^4 + \Delta\alpha_{22}^* P_2^4 + \Delta\alpha_{33}^* P_3^4 \\ & + \Delta\alpha_{12}^* P_1^2 P_2^2 + \Delta\alpha_{13}^* P_1^2 P_3^2 + \Delta\alpha_{23}^* P_2^2 P_3^2 + G_0(\mathbf{P}'), \\ \alpha_1^* = & \alpha_1 + \frac{u_{m1}(Q_{12}s_{12} - Q_{11}s_{22}) + u_{m2}(Q_{11}s_{12} - Q_{12}s_{11})}{(s_{11}s_{22} - s_{12}^2)},\end{aligned}$$

$$\Delta\alpha_{11}^* = \frac{Q_{12}^2 s_{11} + Q_{11}^2 s_{22} - 2Q_{11}Q_{12}s_{12}}{2(s_{11}s_{22} - s_{12}^2)},$$

$$\alpha_2^* = \alpha_1 + \frac{u_{m1}(Q_{22}s_{12} - Q_{12}s_{22}) + u_{m2}(Q_{12}s_{12} - Q_{22}s_{11})}{(s_{11}s_{22} - s_{12}^2)},$$

$$\Delta\alpha_{22}^* = \frac{Q_{22}^2 s_{11} + Q_{12}^2 s_{22} - 2Q_{12}Q_{22}s_{12}}{2(s_{11}s_{22} - s_{12}^2)},$$

$$\alpha_3^* = \alpha_1 + \frac{u_{m1}(Q_{23}s_{12} - Q_{12}s_{22}) + u_{m2}(Q_{12}s_{12} - Q_{23}s_{11})}{(s_{11}s_{22} - s_{12}^2)},$$

$$\Delta\alpha_{33}^* = \frac{Q_{23}^2 s_{11} + Q_{12}^2 s_{22} - 2Q_{12}Q_{23}s_{12}}{2(s_{11}s_{22} - s_{12}^2)},$$

$$\begin{aligned}\Delta\alpha_{12}^* = & \frac{Q_{12}(Q_{22}s_{11} - Q_{12}s_{12}) + Q_{11}(Q_{12}s_{22} - Q_{22}s_{12})}{(s_{11}s_{22} - s_{12}^2)} \\ & + \frac{Q_{66}^2}{2s_{66}},\end{aligned}$$

$$\Delta\alpha_{13}^* = \frac{Q_{12}(Q_{23}s_{11} - Q_{12}s_{12}) + Q_{11}(Q_{12}s_{22} - Q_{23}s_{12})}{(s_{11}s_{22} - s_{12}^2)},$$

$$\Delta\alpha_{23}^* = \frac{Q_{12}(Q_{12}s_{22} - Q_{23}s_{12}) + Q_{22}(Q_{23}s_{11} - Q_{12}s_{12})}{(s_{11}s_{22} - s_{12}^2)}, \quad (1)$$

where α_1 is the dielectric stiffness coefficient, s_{ln} and Q_{ln} are the elastic compliances at constant polarization and electrostrictive constants, respectively, defined in the film reference frame (Voigt matrix notations is used). The misfit strains u_{m1} and u_{m2} can be calculated as $u_{m1}=(a_1-a_0)/a_0$, $u_{m2}=(a_2-a_0)/a_0$, where a_0 is the equivalent cubic cell constant of the freestanding film, a_1 and a_2 are the in-plane lattice constants of the epitaxial film. The part of the modified potential $G_0(\mathbf{P}')$ depending only on polarization components can be expressed as

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$$\begin{aligned}
G_0(\mathbf{P}') = & \alpha_{11}(P_1'^4 + P_2'^4 + P_3'^4) + \alpha_{12}(P_1'^2 P_2'^2 + P_1'^2 P_3'^2 + P_2'^2 P_3'^2) + \alpha_{111}(P_1'^6 + P_2'^6 + P_3'^6) + \alpha_{112}[P_1'^2(P_2'^4 + P_3'^4) + P_2'^2(P_1'^4 \\
& + P_3'^4) + P_3'^2(P_1'^4 + P_2'^4)] + \alpha_{123}P_1'^2 P_2'^2 P_3'^2 + \alpha_{1111}(P_1'^8 + P_2'^8 + P_3'^8) + \alpha_{1122}(P_1'^4 P_2'^4 + P_1'^4 P_3'^4 + P_2'^4 P_3'^4) \\
& + \alpha_{1112}[P_1'^6(P_2'^2 + P_3'^2) + P_2'^6(P_1'^2 + P_3'^2) + P_3'^6(P_1'^2 + P_2'^2)] + \alpha_{1123}(P_1'^4 P_2'^2 P_3'^2 + P_1'^2 P_2'^4 P_3'^2 + P_1'^2 P_2'^2 P_3'^4), \quad (2)
\end{aligned}$$

where α_{ij} , α_{ijk} , and α_{ijkl} are the higher order dielectric stiffness coefficients at constant stress, P'_i are the polarization components in the crystallographic reference frame (x'_1, x'_2, x'_3) which can be obtained from the ones in the film frame by using the transformation $P'_i = A_{ij}P_j$ with the matrix \mathbf{A} given by

$$\mathbf{A} = \begin{pmatrix} 1 & 0 & 0 \\ 0 & 1/\sqrt{2} & -1/\sqrt{2} \\ 0 & 1/\sqrt{2} & 1/\sqrt{2} \end{pmatrix}. \quad (3)$$

In its turn, the material constants Q_{ln} and s_{ln} in full tensor notation can be expressed through the ones defined in the crystallographic reference frame as Q_{mnpq}

$= A_{mi}^{-1} A_{nj}^{-1} A_{qk}^{-1} A_{pl}^{-1} Q'_{ijkl}$, $s_{mnpq} = A_{mi}^{-1} A_{nj}^{-1} A_{qk}^{-1} A_{pl}^{-1} s'_{ijkl}$, where \mathbf{A}^{-1} is the inverse of \mathbf{A} .

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